



Features

- High vacuum to 10⁻⁷ torr
- High stability operation from 2 K to 475 K
- Active cryogenic control of the cold head and radiation shields
- Measurements from DC to 67 GHz
- Accommodates up to 51 mm (2 in) diameter wafers
- Configurable with up to six micro-manipulated probe arms
- Probe arms with 3-axis adjustments and ±5° theta planarization
- Sample stage with ±5° in-plane rotation
- Cables, shields, and guards minimize electrical noise and thermal radiation losses
- High resolution optical system
- Non-magnetic vibration isolation table
- Options and accessories for customization to specific research needs

Model HVTTP6 Probe Station

Introduction

The Model HVTTP6 is a versatile cryogenic, high vacuum micro-manipulated probe station used for non-destructive testing of devices on full and partial wafers up to 51 mm (2 in) in diameter. The HVTTP6 is a platform for measurement of electrical, electro-optical, parametric, high Z, DC, RF, and microwave properties of materials and test devices. Nanoscale electronics, quantum wires and dots, and semiconductors are typical materials measured in a HVTTP6. A wide selection of probes, cables, sample holders, and options makes it possible to configure the HVTTP6 to meet your specific measurement applications.

The HVTTP6 provides vacuum to 10^{-7} torr. The high vacuum insures that condensation does not accumulate in the sample environment during cool down. This is critical for measuring organic semiconductors and for high Z and low current measurement applications.

The HVTTP6 operates over a temperature range of 4.2 K to 475 K. With options, the base temperature can be extended down to 2 K. The probe station provides efficient temperature operation and control with a continuous refrigeration system using either helium or nitrogen. Vapor-cooled shielding optimizes efficiency and intercepts blackbody radiation before it reaches the sample. A control heater on the cold head minimizes temperature gradients across the sample and, along with the radiation shield heaters, provides the probe station with fast thermal response.

The HVTTP6 is user configured with up to six ultra-stable micro-manipulated probe arms. Each arm provides precise 3-axis control of the probe position to accurately land the probe tip on device features. The sample stage provides in-plane rotation to allow alignment of patterns with stage axes. Proprietary probe tips in a variety of sizes and materials minimize thermal mass and optimize electrical contacts to the device under test (DUT). Probe tips are thermally linked to the cold head to minimize heat transfer to the DUT.

For increased versatility, HVTTP6 options include a 2 K base temperature stage, vibration isolation systems, LN_2 Dewar kit, higher magnification monoscopes, vacuum turbo pumping system, and fiber optic probe arm modification.

Headquarters and Sales

Lake Shore Cryotronics, Inc. 575 McCorkle Boulevard
Westerville, Ohio 43082 Phone 614-891-2244
Fax 614-818-1600 <u>info@lakeshore.com</u> All specifications subject to change. Rev 7/17/2007



Applications

- Electrical and electro-optical measurements over a wide temperature range
- RF and microwave
- Parametric testing
- Shielded/guarded/low noise characterization
- High Z
- Non-destructive, full wafer testing

Materials

- Nanoscale electronics (carbon nanotube transistors, single electron transistors, molecular electronics, nanowires, etc.)
- Quantum wires and dots, quantum tunneling
- Single electron tunneling (Coulomb blockade)
- Basic semiconductor devices including organics, LEDs, and dilute magnetic semiconductors

Specifications

Vacuum

Radiation shields at room temperature with DUT baked to 475 K	10 ⁻⁵ torr
Room temperature	10 ⁻⁶ torr
Cold radiation shields with DUT baked to 475 K	10 ⁻⁶ torr
Cold radiation shields with DUT at room temperature	10 ⁻⁷ torr

Temperature

Operating temperature range—overall	2 K to 475 K*
ZN50 DC/RF probe with low RF cryogenic coax cable	2 K to 475 K*
ZN50 DC/RF probe with high RF semirigid coax cable	2 K to 400 K*
GSG microwave probe with semirigid coax cable	2 K to 400 K*
Temperature control (heaters)	
Cold head stage	100 W
Radiation shields	100 W and 50 W
Probe arm	Measurement only
*Salactable aguinment	

*Selectable equipment

Probe Arm and Sample Stage Adjustments

Travel		
X axis	51 mm (2 in)	
Y axis	25 mm (1 in)	
Z axis	18 mm (0.7 in)	
Translation resolution		
X axis	20 µm	
Y and Z axes	10 µm	
Theta planarization*	±5°	
Sample stage (sample holder) in-plane rotation	±5°	

* Included with microwave probes



Frequency Range

ZN50 DC/RF probe frequency range	
Tungsten with cryogenic coax cable	0 to 50 MHz*
Tungsten with semirigid coax cable	0 to 1 $GHz^{*\dagger}$
Paliney 7 with cryogenic coax cable	0 to 50 MHz*
Paliney 7 with semirigid coax cable	0 to 1 $GHz^{*\dagger}$
BeCu with cryogenic coax cable	0 to 50 MHz*
BeCu with semirigid coax cable	0 to 1 $GHz^{*^{\dagger}}$
GSG microwave probe frequency range	
Low frequency with K connector	0 to 40 GHz*
Mid frequency with 2.4 mm connector	0 to 50 GHz*
High frequency with 1.8 mm connector	0 to 67 GHz*

*Selectable equipment

⁺ S21 > -10 dB up to 1 GHz, except for a (-40 dB) spike between 400 MHz and 800 MHz depending on probe model and placement; S11 < -3 dB up to 1 GHz

Optical

Optical viewport—located on top lids	Ø54 mm (2.1 in) outer window and Ø51 mm (2 in) inner window		
Outer, clear fused quartz	99% IR transmittance		
Inner	IR absorbing with narrow band visible light transmittance		
Optical resolution—monoscope			
7:1 zoom	5 µm		
12.5:1 zoom	4 μm*		
16:1 zoom	3 µm*		

*Selectable equipment

Sample Holder (Chuck)

Maximum sample size—overall	Up to Ø51 mm (2 in)
SH-1.25-G, Grounded chuck	Up to Ø31.8 mm (1.25 in) and 475 K
SH-1.25-I, Isolated chuck	Up to Ø31.8 mm (1.25 in) and 400 K*
SH-1.25-C, Coaxial chuck	Up to Ø31.8 mm (1.25 in) and 400 K*
SH-1.25-T, Triaxial chuck	Up to Ø31.8 mm (1.25 in) and 400 K*
SH-2.00-G, Grounded chuck	Up to Ø51 mm (2 in) and 475 K*
SH-2.00-C, Coaxial chuck	Up to Ø51 mm (2 in) and 400 K*
SH-2.00-T, Triaxial chuck	Up to Ø51 mm (2 in) and 400 K*

*Selectable equipment



Standard Equipment

Open cycle multi-stage refrigerator	4.2 K to 475 K		
Cold head stage temperature sensor	Lake Shore Model DT-670-SD-1.4H calibrated silicon diode		
Cold head stage heater	100 W		
Cooled radiation shield and cooled IR-absorbing with	ndow above the sample		
Two radiation shield temperature sensors	Lake Shore Model DT-670C-CU silicon diode		
Two radiation shield heaters	100 W and 50 W		
Removable top lid with viewport	Ø51 mm (2 in) window		
Temperature controllers Two Lake Shore Model 332Ss and one Model 142 200 W			
	(2 channels, 100 W each) power supply (independent regulation of cold head stage, radiation shields, and probe arm temperature monitoring)		
Vacuum chamber Diameter	25.4 cm (10 in)		
Removable top lid with clear fused quartz viewport	Ø54 mm (2.1 in) window		
Probe ports	6 surround the sample thermal radiation shield		
Machined aluminum base plate	53.3 cm ² (21 in ²)		
Vibration isolation table	Low vibration, non-magnetic stand, PVC construction with sand- weighted legs and brass fittings		
Six XYZ precision micro-manipulated probing stages	S		
Probe arms, thermal radiation shields, stainless ste	el welded bellows, and feedthrough ports		
ermally linked probe mounts Probe mounts and radiation shield are thermally anchored to cold head; one probe mount includes a platinum temperatur sensor installed and wired to a 6-pin feedthrough			
Grounded sample holder	SH-1.25-G, accommodates up to a Ø31.8 mm (1.25 in) sample with a Ø25.4 mm (1 in) probe area		
Optics			
Zoom 70 monoscope	7:1 zoom with 5 µm resolution		
Color CCD camera			
Swing arm	Optics can be manipulated to view any part of the sample or wafer, and can be retracted and swung away to allow access to the top of the vacuum chamber for sample exchange		
Video monitor	High resolution, 17-inch		
Sample illumination	Coaxial via fiber optic or ring light from an adjustable light source and power supply (must specify sample illumination at time of order) NOTE: Coaxial illumination is recommended for highly reflective materials		
High efficiency helium transfer line with foot valve	for precise flow regulation		
Instrument console			
Basic tools, spares, and cleaning kit			



Probes, Probe Tips, and Cables — Required User Configurable Equipment

ZN50 DC/RF PROBES

- Ideal for: DC biasing, low/high frequency measurements, low noise shielded, and low-leakage guarded measurement
- ZN50 probe base incorporates a pair of copper braids that connect to the sample stage to dynamically cool/heat the probe to the sample temperature
- SMA connector mounted directly to a replaceable alumina ceramic blade with
- a 50 Ω stripline routed to the probe contact

Part number (probe body)	Description
ZN50-26U	50 Ω stripline probe body mount (each probe body mount requires a ceramic blade—selectable below)

We understand that today's researcher requires flexibility. Our wide selection of probes, cables, sample holders, and options make it possible to configure a probe station to meet your specific measurement applications.

Part number (ceramic blade)	Tip material	Maximum frequency (GHz)	Tip radius (µm)
ZN50R-03-W			3
ZN50R-10-W	Tungsten		10
ZN50R-25-W			25
ZN50R-03-P7			3
ZN50R-10-P7	Paliney 7		10
ZN50R-25-P7		1*	25
ZN50R-03-BeCu			3
ZN50R-10-BeCu	BeCu		10
ZN50R-25-BeCu			25
ZN50R-100-BeCu			100
ZN50R-200-BeCu			200

*Maximum frequency 50 MHz with Z50-CU-SS-3650-G or Z50-CU-SS-3650-T cable; maximum frequency 1 GHz with K-085-K cable

ZN50 DC/RF CABLES

Part number	Cable type	Connector type	Feedthrough type	Measurement configuration	Maximum frequency	Maximum temperature
Z50-CU-SS-3650-G	Ultra-miniature cryogenic coax	SMA	BNC	Shielded	50 MHz	475 K
Z50-CU-SS-3650-T	Ultra-miniature cryogenic coax	SMA	2-lug triax	Low leakage	50 MHz	475 K
K-085-K-09	Stainless semirigid microwave coax	К	Loss-less compression seal	High frequency	1 GHz*	400 K

* S21 > -10 dB up to 1 GHz, except for a (-40 dB) spike between 400 MHz and 800 MHz depending on probe model and placement; S11 < -3 dB up to 1 GHz



GSG MICROWAVE PROBES

- Coplanar waveguide probe with ground-signal-ground (GSG) contact geometry
- User-specified pitch (spacing)
- Optimized low thermal conductivity coax leading to low thermal conductivity tips
- Include a copper braid assembly to cool the probe to near sample temperature
- Separate theta planarization module with ±5° rotation mechanism is also provided

Part number	Connector type	Maximum frequency (GHz)	Pitch (µm)
GSG-050-40A-26U-D			50
GSG-100-40A-26U-D			100
GSG-150-40A-26U-D	К	40	150
GSG-200-40A-26U-D			200
GSG-250-40A-26U-D			250
GSG-050-50A-26U-D	2.4 mm		50
GSG-100-50A-26U-D		50	100
GSG-150-50A-26U-D			150
GSG-200-50A-26U-D			200
GSG-250-50A-26U-D			250
GSG-050-67A-26U-D			50
GSG-100-67A-26U-D			100
GSG-150-67A-26U-D	1.8 mm	67	150
GSG-200-67A-26U-D			200
GSG-250-67A-26U-D			250

GSG MICROWAVE CABLES

- Loss-less compression seal
- Semirigid with stainless steel outer jacket, silver plated BeCu inner conductor, and Teflon[®] dielectric

Part number	Cable type	Feedthrough type	Maximum temperature	Connector type	Maximum frequency
K-085-K-09	Chainlana anniniaid	Loss-less		K	40 GHz
2.4-085-2.4-09	Stainless semirigid	compression	400 K	2.4 mm	50 GHz
1.8-085-1.85-09	microwave coax	seal		1.8 mm	67 GHz



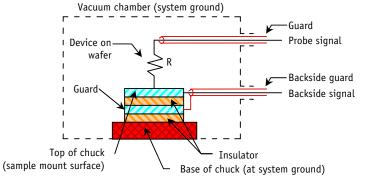
SAMPLE HOLDERS (CHUCKS)

Typical sample holder configuration characterized by:

- Leakage resistance between
 - Top surface and guard
 - Guard and ground
- Capacitance between
 - Top surface and guard
 - Guard and ground

Types of sample holders

 Grounded sample holder—sample mount surface at system ground



- Isolated sample holder—backside contact not needed; sample mount surface is electrically non-conductive and isolated from ground
- Coaxial sample holder—backside contact can be made; sample mount surface is isolated from ground
- Triaxial sample holder—guarded backside contact can be made; sample mount surface has guarded isolation from ground

Part number	Measurement configuration	Separate feedthrough required	Maximum sample (diameter)	Maximum temperature
SH-1.25-G	Grounded	No	Ø31.8 mm (1.25 in)	475 K
SH-1.25-I	Isolated			400 K
SH-1.25-C	Coaxial	Yes*		
SH-1.25-T	Triaxial	Yes**		
SH-2.00-G	Grounded	No	Ø51 mm (2 in)	475 K
SH-2.00-C	Coaxial	Yes*		400 K
SH-2.00-T	Triaxial	Yes**		

*Coaxial sample holders require one FT-BNC or FT-TRIAX feedthrough as listed below

**Triaxial sample holders require one FT-TRIAX feedthrough as listed below

Part Number	Description
FT-BNC	Coaxial feedthrough and coax cable, installed and wired
FT-TRIAX	Triaxial feedthrough and coax cable, installed and wired

Equipment Options

Part number	Description		
PS-FOA	Fiber optic probe arm modification. Transmit or receive light or IR/UV radiation. Fiber optic terminated with SMA connector or compression feedthrough. (Fiber optic wire not included. Fiber optic and probe cannot be used simultaneously.)		
PS-Z12.5	12.5:1 zoom monoscope upgrade for 4 µm resolution NOTE: upgrade is not field-installable		
PS-Z16	16:1 zoom monoscope upgrade for 3 µm resolution NOTE: upgrade is not field-installable		
PS-2K	2.0 K base temperature stage pumping option—includes system modifications, stainless steel flex hose for pump connection, and Edwards E1M18 rotary pump (14.7 CFM at 60 Hz with oil mist eliminator on output [with oil return], and inlet oil demister)		
PS-DPC	Automatic Dewar (gas) pressure controller, regulates Dewar liquid flow		
PS-V301TP	Turbo pumping system — includes Varian V-301 Turbo Pump cart with SH 110 backing pump and controller (specify 110 V/60 Hz or 220 V/50 Hz)		
PS-V301DP	Turbo pumping system — includes Varian V-301 Turbo Pump cart with DS 102 oil free backing pump and controller (specify 110 V/60 Hz or 220 V/50 Hz)		
PS-LN2	Nitrogen Dewar with stainless fittings, gauges, and adaptors; allows LN ₂ use with the LHe transfer line		
PS-PLVI-40	Pump-line vibration isolator—includes NW-40 fittings, 1 m stainless steel bellows, clamps, and rings (placed between pump cart and system); requires one bag of cement		



Equipment Options, continued

Part Number	Description		
PS-TTVIS	Pneumatic tabletop vibration isolation system—compact pneumatic isolator with self-leveling (isolator resonance: vertical 3.2 Hz, horizontal 3.6 Hz; isolation efficiency at 10 Hz: vertical 90%, horizontal 96%; amplification at resonance: vertical 12 dB, horizontal 10 dB); 80 psi nitrogen or air		
PS-TMC-B	Stand with pneumatic vibration isolation system (gimbal piston isolator, actuators, and supports)(isolator natural frequency: vertical 0.8 Hz, horizontal 1.0 Hz; isolation efficiency at 5 Hz: vertical 80 to 97%, horizontal 60 to 90%; isolation efficiency at 10 Hz: vertical 90 to 99%, horizontal 70 to 95%); requires 80 psi nitrogen or air		
PS-0AC	Oil-less compressor for PS-TTVIS or PS-TMC-B (only available in 110 V)		
PA-SEN	Probe arm modification with platinum temperature sensor installed and wired to a 6-pin feedthrough		
PA-HVTTP6	Probe arm and base for HVTTP6		
MMS-HVTTP6	Micro-manipulated stage for HVTTP6		
CS-5	Calibration substrate for GSG probes — pad size: 50 μm ² ; calibration type: SOLT (short-open-load-through), LRL (line-reflective-line), LRM (line-reflective-match); pitch range: 75 to 250 μm		
CS-15	Calibration substrate for GSG probes. Pad size: 25 μm ² ; calibration type: SOLT (short-open-load-through), LRL (line-reflective-line), LRM (line-reflective-match); pitch range: 40 to 150 μm		

Lake Shore Cryotronics is a leading supplier of cryogenic, superconducting magnet-based, electromagnet-based, high vacuum, and load-lock probe stations. We offer a full line of standard probe stations to meet your research requirements.

Our standard line of probe stations includes:

Model TTP4

- Up to four micro-manipulated probe stages
- Temperature range capabilities from 3.2 K to 475 K
- Up to 51 mm (2 in) diameter wafer capabilities

Model TTP4-1.5K

- Up to four micro-manipulated probe stages
- Standard temperature range from 1.5 K to 475 K
- Up to 25 mm (1 in) diameter wafer capabilities

Model TTP6

- Up to six micro-manipulated probe stages
- Temperature range capabilities from 3.2 K to 475 K
- Up to 51 mm (2 in) diameter wafer capabilities

Model FWP6

- Up to six micro-manipulated probe stages
- Standard temperature range from 4.5 K to 475 K
- Up to 10.2 cm (4 in) diameter wafer capabilities

Model LLTTP6

- Load-lock for fast sample exchange at any temperature
- Up to six micro-manipulated probe stages
- Standard temperature range from 10 K to 400 K
- Up to 51 mm (2 in) diameter wafer capabilities; up to 12.7 mm (0.5 in) with load-lock assembly

Model HFTTP4

- 1 T horizontal field split pair superconducting magnet
- Up to four micro-manipulated probe stages
- Temperature range capabilities from 2 K to 400 K with field on or off
- Up to 25 mm (1 in) diameter wafer capabilities

Model VFTTP4

- 2.5 T vertical field solenoid superconducting magnet
- Up to four micro-manipulated probe stages
- Temperature range capabilities from 2 K to 400 K with field on or off
- Up to 51 mm (2 in) diameter wafer capabilities

Model EMTTP4

- 0.55 T horizontal (in-plane field) electromagnet
- Up to four micro-manipulated probe stages
- Standard temperature range from 5 K to 475 K
- Up to 25.4 mm (1 in) diameter wafer capabilities

Model HVTTP6

- High vacuum to 10⁻⁷ torr
- Up to six micro-manipulated probe stages
- Temperature range capabilities from 2 K to 475 K
- Up to 51 mm (2 in) diameter wafer capabilities